TOSHIBA Photocoupler GaAs IRed & Photo-Transistor

TLP630

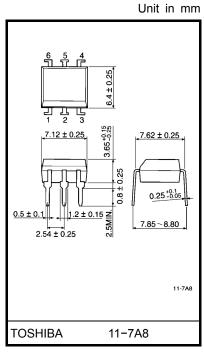
Programmable Controllers
AC / DC-Input Module
Telecommunication

The TOSHIBA TLP630 consists of a photo-transistor optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel in a six lead plastic DIP package.

- Collector-emitter voltage: 55V min.
- Current transfer ratio: 50% min.

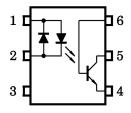
Rank GB: 100% min.

- Isolation voltage: 5000Vrms min.
- UL recognized: UL1577 file no. E67349



Weight: 0.4g

Pin Configurations(top view)



1 : ANODE, CATHODE 2 : CATHODE, ANODE

3 : N.C.

4 : EMITTER 5 : COLLECTOR

6: BASE

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
	Forward current	I _{F(RMS)}	60	mA
LED	Forward current derating (Ta ≥ 39°C)	ΔI _F / °C	-0.7	mA / °C
	Peak forward current (100µs pulse,100pps)	I _{FPT}	±1	А
	Collector-emitter voltage	V _{CEO}	55	V
	Collector-base voltage	V _{CBO}	80	V
ctor	Emitter-collector voltage	V _{ECO}	7	٧
Detector	Emitter-base voltage	V _{EBO}	7	٧
	Collector current	Ic	50	mA
	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C / °C	-1.5	mW / °C
Оре	erating temperature range	T _{opr}	-55~100	°C
Sto	rage temperature range	T _{stg}	-55~125	°C
Lead soldering temperature		T _{sol}	260(10s)	°C
Junction temperature		Tj	125	°C
Total package power dissipation		PT	250	mW
	al package power dissipation ating	ΔP _T / °C	-2.5	mW / °C
Isolation voltage (AC, 1 min., R.H. ≤ 60%)		BVS	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{CC}	_	5	24	V
Forward current	I _{F(RMS)}	_	16	25	mA
Collector current	IC	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

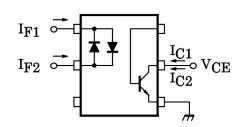
Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10mA	1.0	1.15	1.3	V
	Forward current	lF	V _F = 0.7V	_	2.5	10	μΑ
	Capacitance	C _T	V = 0, f = 1MHz	_	60	_	pF
Detector	Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 0.5mA	55	-	-	V
	Emitter–collector breakdown voltage	V _{(BR)ECO}	I _E = 0.1mA	7	_	_	V
	Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 0.1mA	80	ı	ı	V
	Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = 0.1mA	7	1	1	V
	Collector doub or mont	I= (I)	V _{CE} = 24V	_	10	100	nA
	Collector dark current	ID(ICEO)	V _{CE} = 24V, Ta = 85°C	_	2	50	μΑ
	Collector dark current	I _{CBO}	V _{CB} = 10V	_	0.1	_	nA
	Capacitance (collector to emitter)	C _{CE}	V = 0, f = 1MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Current transfer ratio	Current transfer ratio $I_C / I_F = \pm 5mA, V_{CE} = 5V$ Rank GB	I _F = ±5mA, V _{CE} = 5V	50	-	600	%
Current transfer fatto		100	-	600	70	
Saturated CTR	$I_C / I_{F(sat)}$ $I_F = \pm 1 \text{mA}, V_{CE} = 0.4 \text{V}$ Rank GB	_	60		%	
		Rank GB	30	-	1	/0
Base photo-current	I _{PB}	$I_F = \pm 5$ mA, $V_{CB} = 5$ V	_	10		μA
Collector–emitter saturation voltage	V _{CE(sat)}	I _C = 2.4mA, I _F = ±8mA	_	ı	0.4	V
Off-state collector current	I _{C(off)}	$V_F = \pm 0.7 V$, $V_{CE} = 24 V$	_	1	10	μA
CTR symmetry	I _{C(ratio)}	$I_{C}(I_{F} = -5mA) / I_{C}(I_{F} = +5mA)$ (Note 1)	0.33	1	3	_

(Note 1)
$$I_{C(ratio)} = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$$



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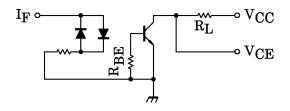
Isolation Characteristics (Ta = 25°C)

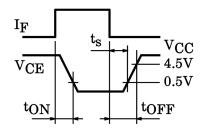
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance (input to output)	CS	V _S = 0, f = 1MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	5000	_	_	Vrms
Isolation voltage	BV_S	AC, 1 second, in oil	_	10000	_	
		DC, 1 minute, in oil	_	10000	_	Vdc

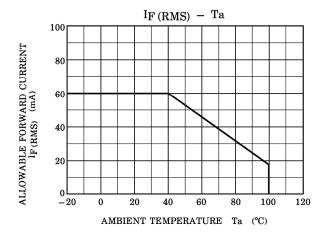
Switching Characteristics (Ta = 25°C)

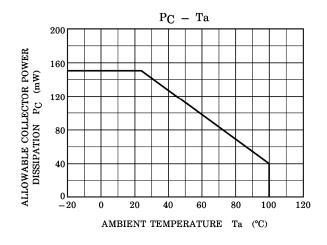
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r		_	2	_	
Fall time	t _f	V _{CC} = 10V, I _C = 2mA	_	3	_	
Turn-on time	t _{ON}	R _L = 100Ω	_	3	_	μs
Turn-off time	t _{OFF}		_	3	_	
Turn-on time	t _{ON}	$R_L = 1.9 \text{ k}\Omega$ (Note 2) - $R_{BE} = \text{OPEN}$ $V_{CC} = 5 \text{ V}, I_F = \pm 16 \text{mA}$	_	2	_	
Storage time	t _S		_	15	_	μs
Turn-off time	t _{OFF}		_	25	_	
Turn-on time	t _{ON}	$R_{L} = 1.9k\Omega$ (Note 2) $R_{BE} = 220k\Omega$, $V_{CC} = 5 V$ $I_{F} = \pm 16mA$	_	2	_	
Storage time	ts		_	12	_	μs
Turn-off time	t _{OFF}		_	20	_	

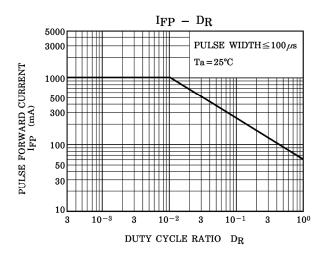
(Note 2) Switching time test circuit

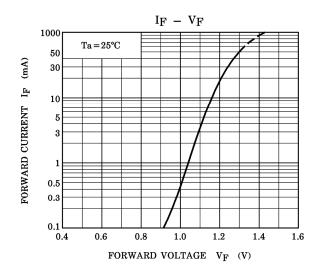


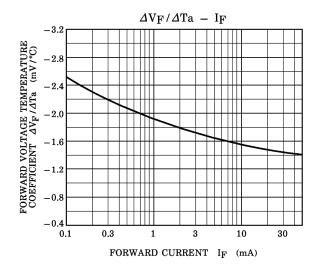


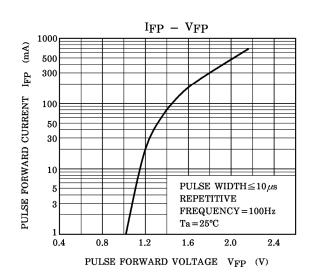


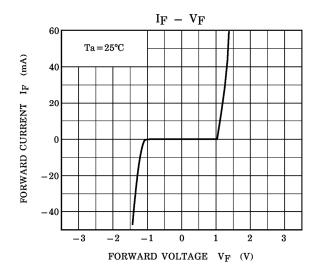


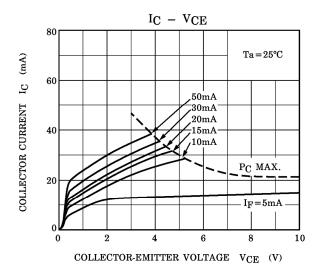


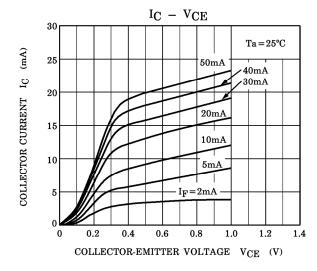


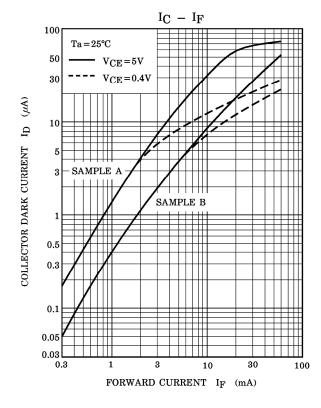


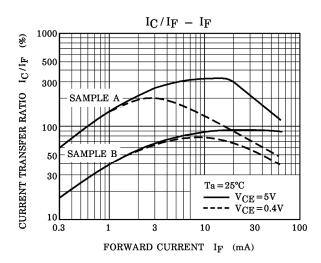




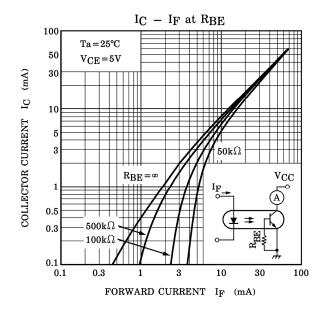


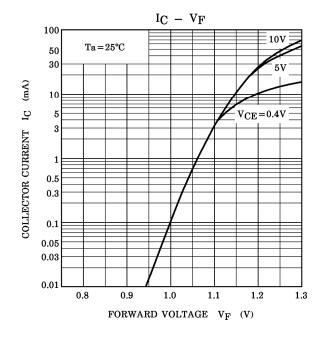


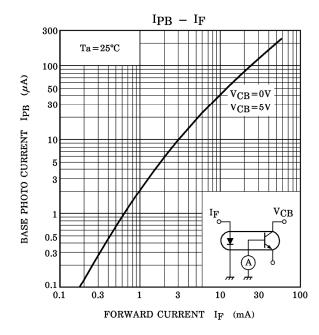


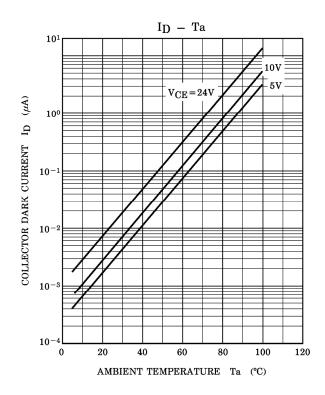


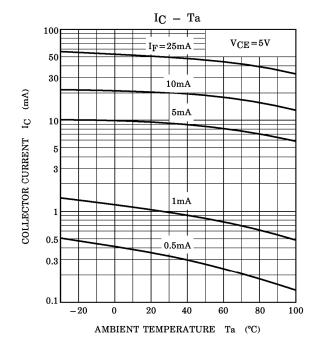
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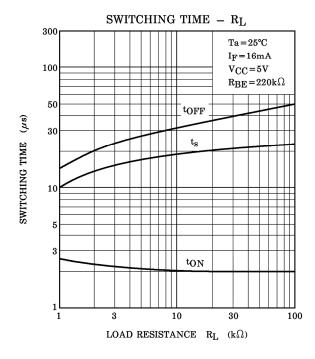


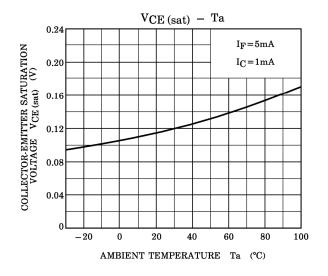


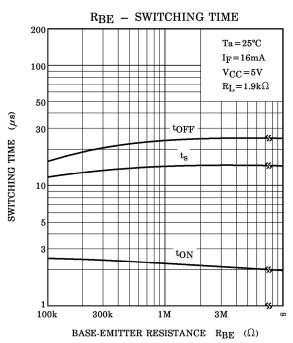


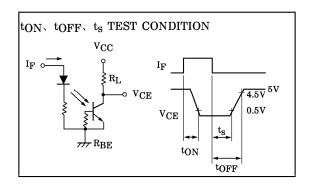












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